TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

2SA1242

Strobe Flash Applications Medium Power Amplifier Applications

- Excellent hFE linearity
 hFE (1) = 100 to 320 (V_{CE} = -2 V, I_C = -0.5 A)
 hFE (2) = 70 (min) (V_{CE} = -2 V, I_C = -4 A)
- Low collector saturation voltage : $V_{CE (sat)} = -1.0 V (max) (I_C = -4 A, I_B = -0.1 A)$
- High power dissipation : $P_C = 10 \text{ W} (T_c = 25^{\circ}\text{C}), P_C = 1.0 \text{ W} (T_a = 25^{\circ}\text{C})$

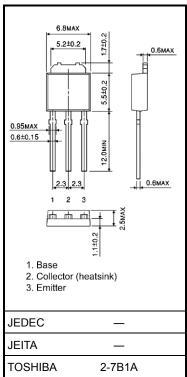
Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	-35	V	
Collector-emitter voltage		V _{CEO}	-20	V	
Emitter-base voltage		V _{EBO}	-8	V	
Collector current	DC	Ι _C	-5	A	
	Pulsed (Note 1)	I _{CP}	-8		
Base current		Ι _Β	-0.5	Α	
Collector power dissipation	Ta = 25°C	Pc	1.0	w	
	Tc = 25°C	ГC	10		
Junction temperature		Тj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Absolute Maximum Ratings (Ta = 25°C)

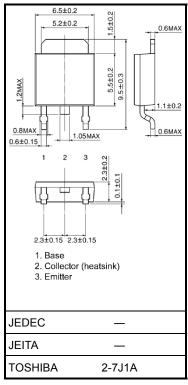
Note 1: Pulse test: Pulse width = 10 ms (max), duty cycle = 30% (max)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 0.36 g (typ.)



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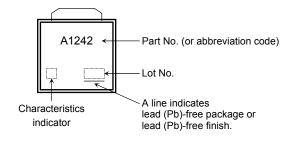
Unit: mm

Electrical Characteristics (Ta = 25°C)

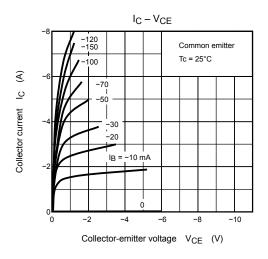
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -35 \text{ V}, \text{ I}_{E} = 0$	_	—	-100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = -8 V, I _C = 0	_	_	-100	nA
Collector-emitter breakdown voltage	V _{CEO}	I _C = -10 mA, I _B = 0	-20	—	_	V
Emitter-base breakdown voltage	V _{EBO}	$I_{E} = -1 \text{ mA}, I_{C} = 0$	-8	_	_	V
DC current gain	h _{FE (1)} (Note 3)	$V_{CE} = -2 V, I_C = -0.5 A$	100	_	320	
	h _{FE (2)}	$V_{CE} = -2 V, I_C = -4 A$	70	_	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = -4 A, I _B = -0.1 A	_	—	-1.0	V
Base-emitter voltage	V _{BE}	$V_{CE} = -2 V, I_C = -4 A$	_	_	-1.5	V
Transition frequency	f _T	V _{CE} = -2 V, I _C = -0.5 A	—	170	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = −10 V, I _E = 0, f = 1 MHz	_	62	_	pF

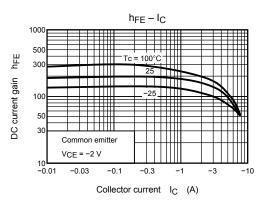
Note 3: h_{FE (1)} classification O: 100 to 200, Y: 160 to 320

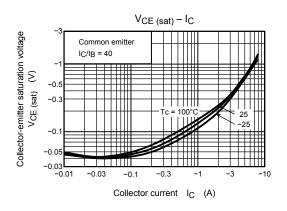
Marking

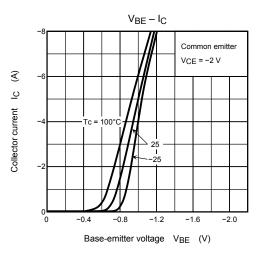


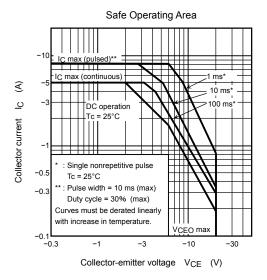
TOSHIBA

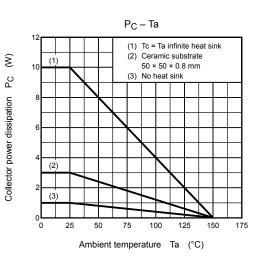












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